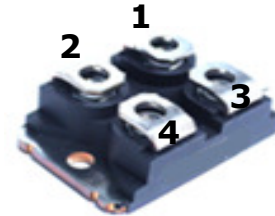
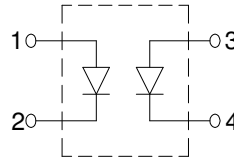




Parallel 2X50A, 1600V Rectifier Diode in SOT227 Package

- High surge capacity
- Low forward voltage
- 150°C maximum junction temperature
- Pb-free lead finish; RoHS compliant



MAXIMUM RATINGS (per diode), at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Units
Repetitive peak reverse voltage	V_{RRM}	1600	V
Continuous forward current $T_C = 70^\circ\text{C}$	I_F	50	A
Surge non-repetitive forward current 10 ms sine pulse, rated V_{RRM} applied $t_p = 10$ ms, No voltage reapplied Half wave sine	I_{FSM}	400 475	
Operating junction and storage temperature	T_j, T_{stg}	-40... +150	$^\circ\text{C}$

Thermal Characteristics (per diode)

Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case	R_{thJC}	0.78	$^\circ\text{C}/\text{W}$
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds)	V_{iso}	3000	V

Electrical Characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Static Characteristics					
Reverse leakage current $V_R = 1600\text{V}$	I_R	-	-	200	μA
Forward voltage drop $I_F = 50\text{A}$	V_F	-	1.1	-	V



Package Outline Drawing

